



STD7NM60N, STF7NM60N STP7NM60N, STU7NM60N

N-channel 600 V, 5 A, 0.84 Ω, DPAK, TO-220FP, TO-220, IPAK
second generation MDmesh™ Power MOSFET

Features

Order codes	V _{DSS} @ T _{Jmax}	R _{DS(on)} max.	I _D
STD7NM60N			
STF7NM60N	650 V	< 0.9 Ω	5 A
STP7NM60N			
STU7NM60N			

- 100% avalanche tested
- Low input capacitance and gate charge
- Low gate input resistance

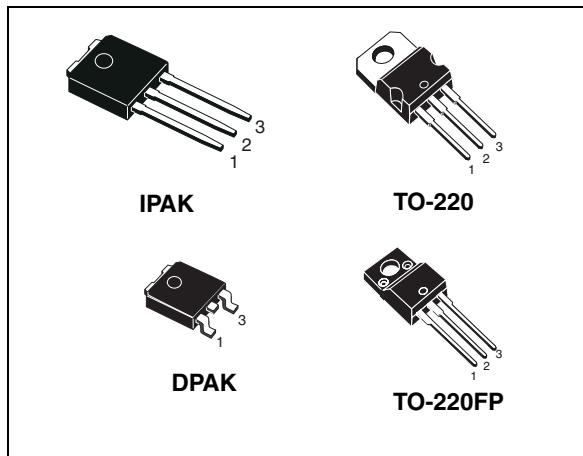


Figure 1. Internal schematic diagram

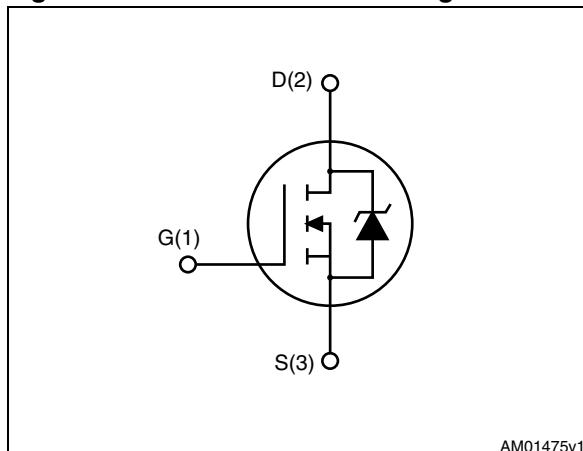


Table 1. Device summary

Order codes	Marking	Package	Packaging
STD7NM60N	7NM60N	DPAK	Tape and reel
STF7NM60N		TO-220FP	Tube
STP7NM60N		TO-220	Tube
STU7NM60N		IPAK	Tube

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1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		TO-220, IPAK, DPAK	TO-220FP	
V_{DS}	Drain-source voltage ($V_{GS} = 0$)	600		V
V_{GS}	Gate-source voltage		± 25	V
I_D	Drain current (continuous) at $T_C = 25^\circ\text{C}$	5	5 ⁽¹⁾	A
I_D	Drain current (continuous) at $T_C = 100^\circ\text{C}$	3	3 ⁽¹⁾	A
$I_{DM}^{(2)}$	Drain current (pulsed)	20	20 ⁽¹⁾	A
P_{TOT}	Total dissipation at $T_C = 25^\circ\text{C}$	45	20	W
$dv/dt^{(3)}$	Peak diode recovery voltage slope		15	V/ns
V_{ISO}	Insulation withstand voltage (RMS) from all three leads to external heat sink ($t = 1 \text{ s}; T_C = 25^\circ\text{C}$)		2500	V
T_{stg}	Storage temperature		- 55 to 150	$^\circ\text{C}$
T_j	Max. operating junction temperature		150	$^\circ\text{C}$

1. Limited only by maximum temperature allowed
2. Pulse width limited by safe operating area
3. $I_{SD} \leq 5 \text{ A}, di/dt \leq 400 \text{ A}/\mu\text{s}, V_{Peak} < V_{(BR)DSS}$

Table 3. Thermal data

Symbol	Parameter	Value				Unit
		DPAK	IPAK	TO-220	TO-220FP	
$R_{thj-case}$	Thermal resistance junction-case max		2.78		6.25	$^\circ\text{C}/\text{W}$
$R_{thj-amb}$	Thermal resistance junction-ambient max		100		62.5	$^\circ\text{C}/\text{W}$
$R_{thj-pcb}$	Thermal resistance junction-pcb max	50				$^\circ\text{C}/\text{W}$
T_I	Maximum lead temperature for soldering purpose			300		$^\circ\text{C}$

Table 4. Thermal data

Symbol	Parameter	Value	Unit
I_{AR}	Avalanche current, repetitive or not-repetitive (pulse width limited by T_j max)	2	A
E_{AS}	Single pulse avalanche energy (starting $T_j = 25^\circ\text{C}$, $I_D = I_{AR}$, $V_{DD} = 50 \text{ V}$)	119	mJ

2 Electrical characteristics

($T_C = 25^\circ\text{C}$ unless otherwise specified)

Table 5. On /off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(\text{BR})\text{DSS}}$	Drain-source breakdown voltage	$I_D = 1 \text{ mA}, V_{GS} = 0$	600			V
I_{DSS}	Zero gate voltage drain current ($V_{GS} = 0$)	$V_{DS} = \text{Max rating}$ $V_{DS} = \text{Max rating}, T_C = 125^\circ\text{C}$			1 100	μA μA
I_{GSS}	Gate-body leakage current ($V_{DS} = 0$)	$V_{GS} = \pm 20 \text{ V}$			100	nA
$V_{GS(\text{th})}$	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	2	3	4	V
$R_{DS(\text{on})}$	Static drain-source on resistance	$V_{GS} = 10 \text{ V}, I_D = 2.5 \text{ A}$		0.84	0.9	Ω

Table 6. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C_{iss}	Input capacitance			363		pF
C_{oss}	Output capacitance	$V_{DS} = 50 \text{ V}, f = 1 \text{ MHz}, V_{GS} = 0$	-	24.6	-	pF
C_{rss}	Reverse transfer capacitance			1.1		pF
$C_{oss \text{ eq.}}^{(1)}$	Output equivalent capacitance	$V_{DS} = 0 \text{ to } 480 \text{ V}, V_{GS} = 0$	-	130	-	pF
R_G	Intrinsic gate resistance	$f = 1 \text{ MHz open drain}$	-	5.4	-	Ω
Q_g	Total gate charge	$V_{DD} = 480 \text{ V}, I_D = 5 \text{ A}, V_{GS} = 10 \text{ V}$		14		nC
Q_{gs}	Gate-source charge		-	2.7	-	nC
Q_{gd}	Gate-drain charge	(see <i>Figure 18</i>)		7.7		nC

1. $C_{oss \text{ eq.}}$ is defined as a constant equivalent capacitance giving the same charging time as C_{oss} when V_{DS} increases from 0 to 80% V_{DS} .

Table 7. Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max	Unit
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 300 \text{ V}$, $I_D = 2.5 \text{ A}$, $R_G = 4.7 \Omega$, $V_{GS} = 10 \text{ V}$ (see Figure 19)	-	7	-	ns
t_r	Rise time			10		ns
$t_{d(off)}$	Turn-off-delay time			26	-	ns
t_f	Fall time			12		ns

Table 8. Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD} $I_{SDM}^{(1)}$	Source-drain current		-		5	A
	Source-drain current (pulsed)				20	A
$V_{SD}^{(2)}$	Forward on voltage	$I_{SD} = 5 \text{ A}$, $V_{GS} = 0$	-		1.3	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time	$I_{SD} = 5 \text{ A}$, $dI/dt = 100 \text{ A}/\mu\text{s}$ $V_{DD} = 60 \text{ V}$ (see Figure 22)	-	213		ns
	Reverse recovery charge			1.5		nC
	Reverse recovery current			14		A
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time	$I_{SD} = 5 \text{ A}$, $dI/dt = 100 \text{ A}/\mu\text{s}$ $V_{DD} = 60 \text{ V}$, $T_j = 150^\circ\text{C}$ (see Figure 22)	-	265		ns
	Reverse recovery charge			1.8		nC
	Reverse recovery current			14		A

1. Pulse width limited by safe operating area
2. Pulsed: pulse duration = 300 μs , duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for DPAK, IPAK **Figure 3.** Thermal impedance for DPAK, IPAK

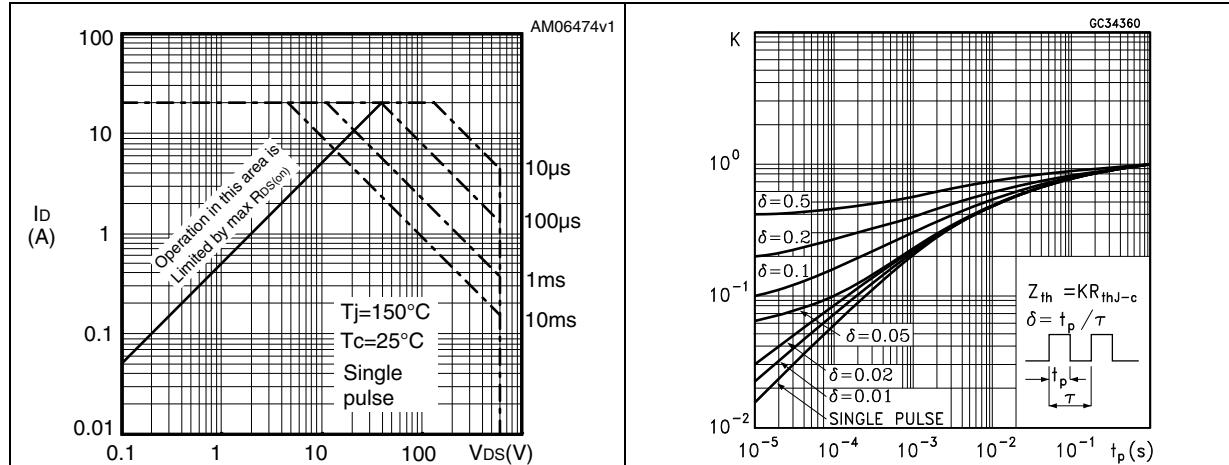


Figure 4. Safe operating area for TO-220FP

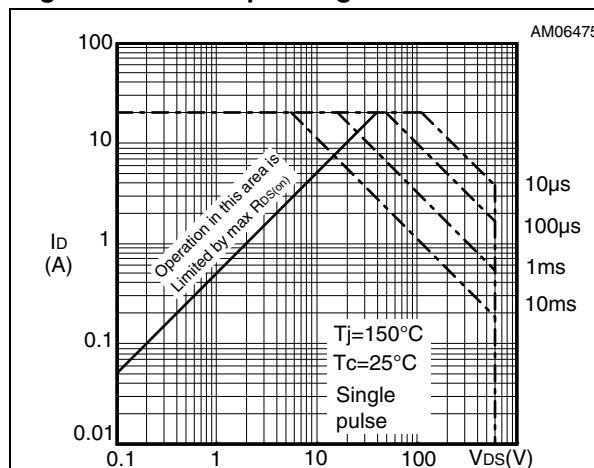


Figure 5. Thermal impedance for TO-220FP

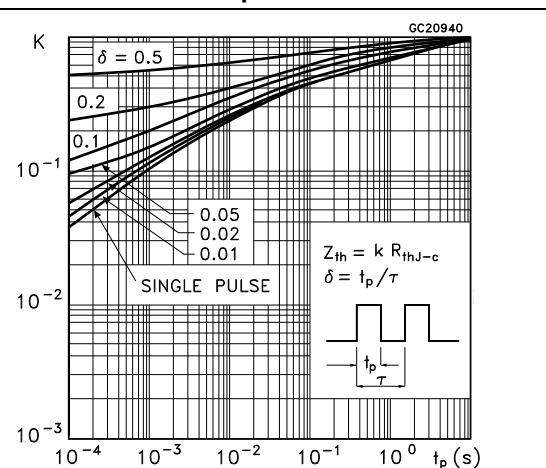


Figure 6. Safe operating area for TO-220

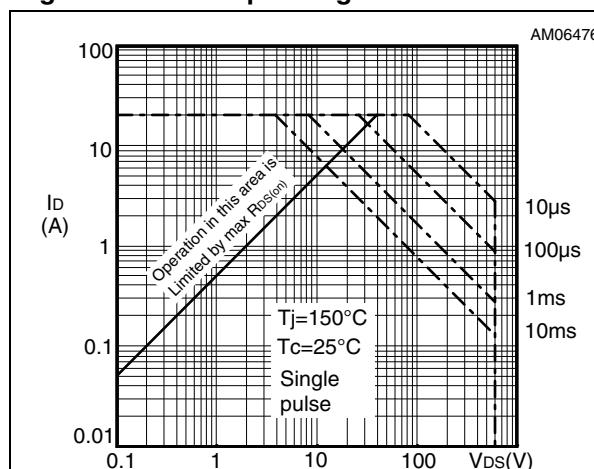


Figure 7. Thermal impedance for TO-220

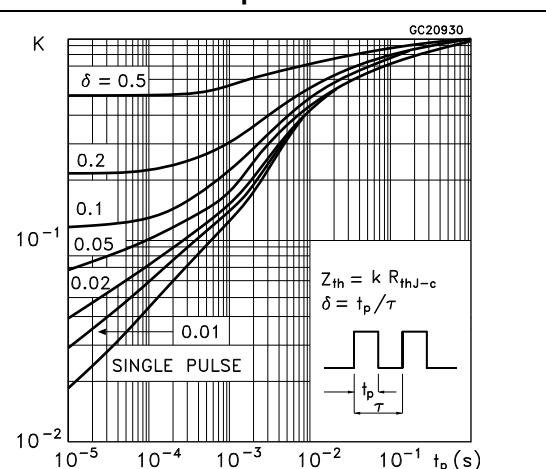


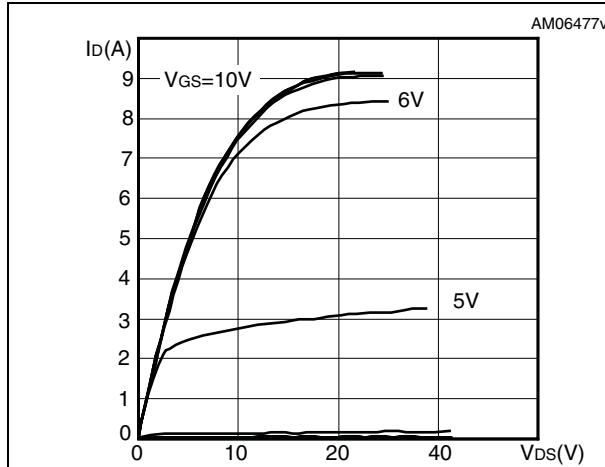
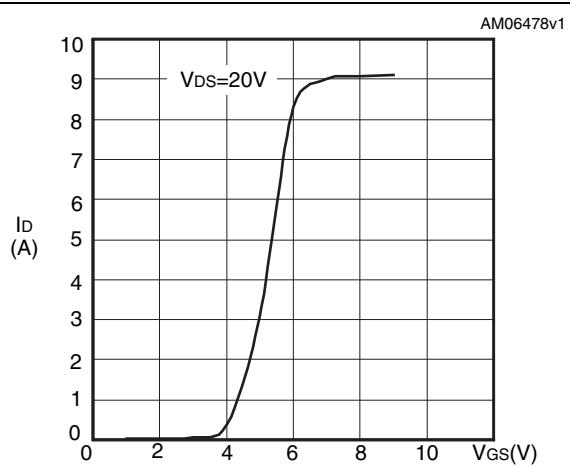
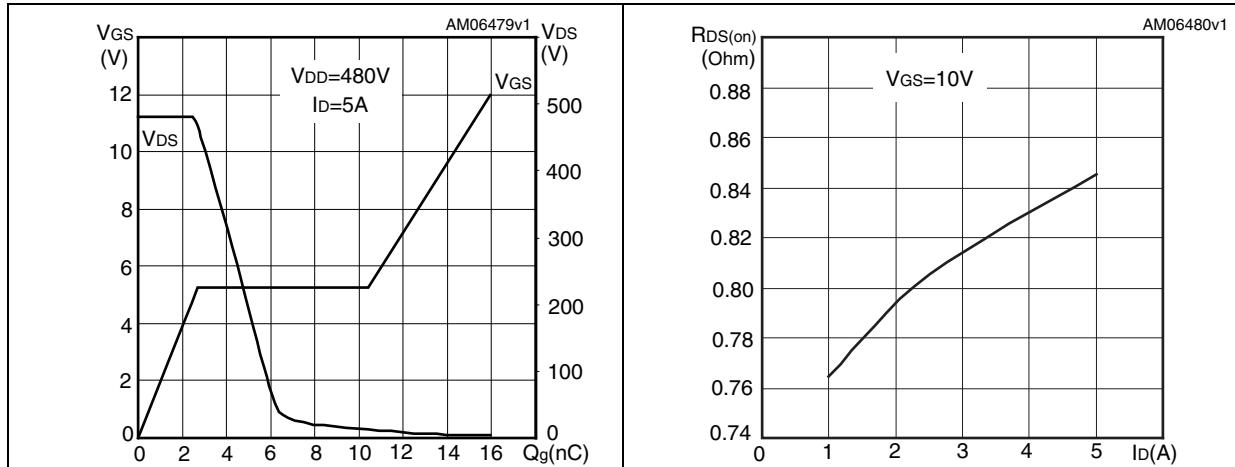
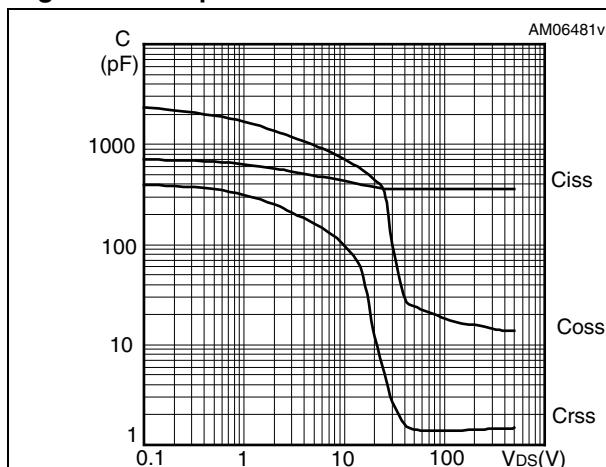
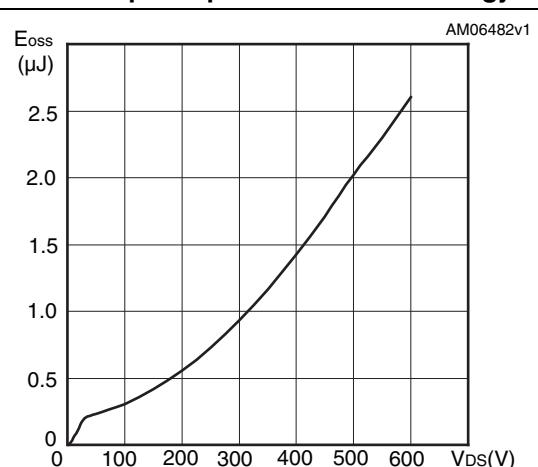
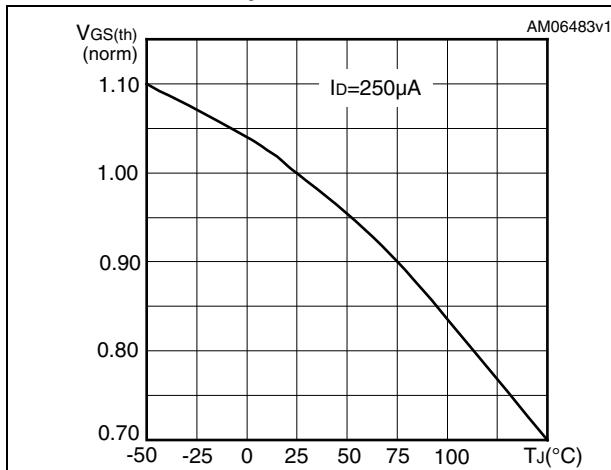
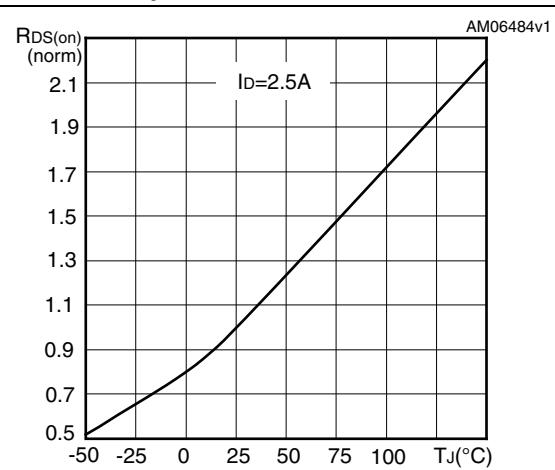
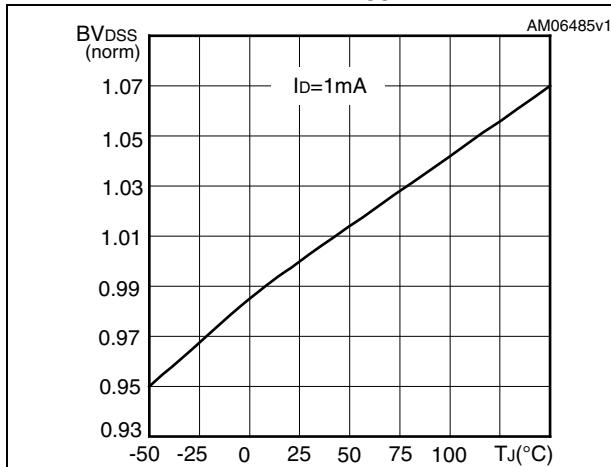
Figure 8. Output characteristics**Figure 9. Transfer characteristics****Figure 10. Gate charge vs gate-source voltage** **Figure 11. Static drain-source on resistance****Figure 12. Capacitance variations****Figure 13. Output capacitance stored energy**

Figure 14. Normalized gate threshold voltage vs temperature**Figure 15. Normalized on resistance vs temperature****Figure 16. Normalized B_{VDSS} vs temperature**

3 Test circuits

Figure 17. Switching times test circuit for resistive load

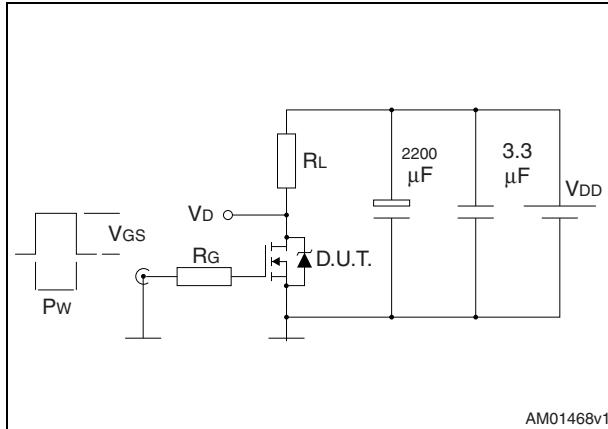


Figure 18. Gate charge test circuit

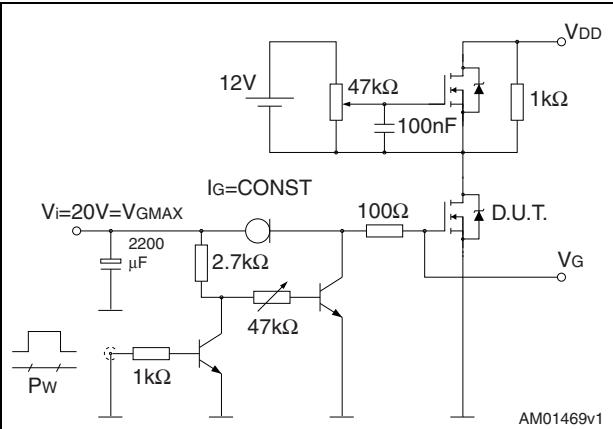


Figure 19. Test circuit for inductive load switching and diode recovery times

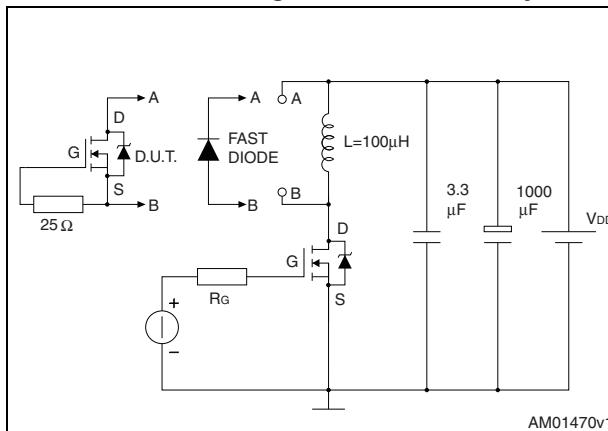


Figure 20. Unclamped inductive load test circuit

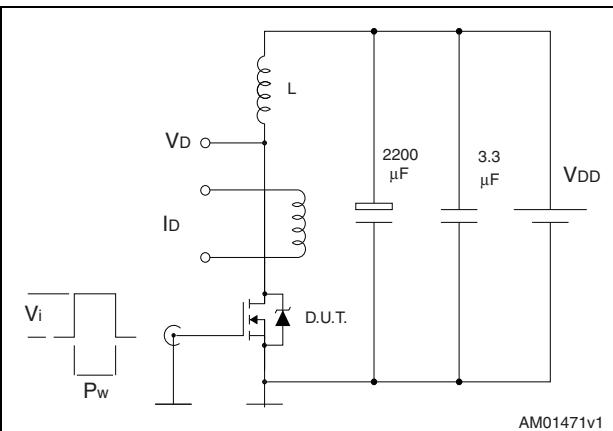


Figure 21. Unclamped inductive waveform

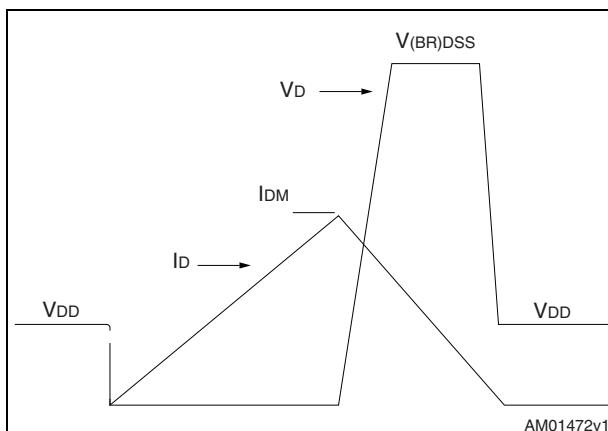
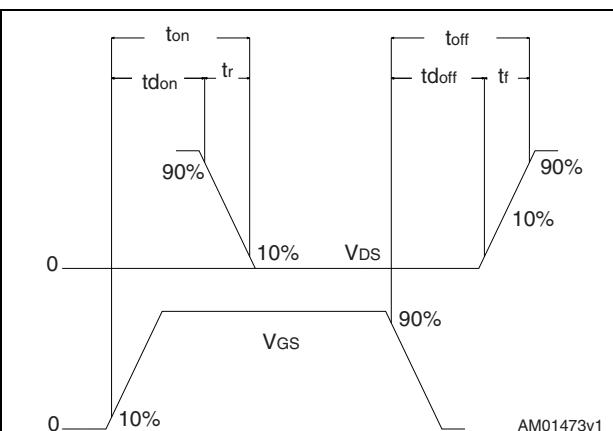


Figure 22. Switching time waveform

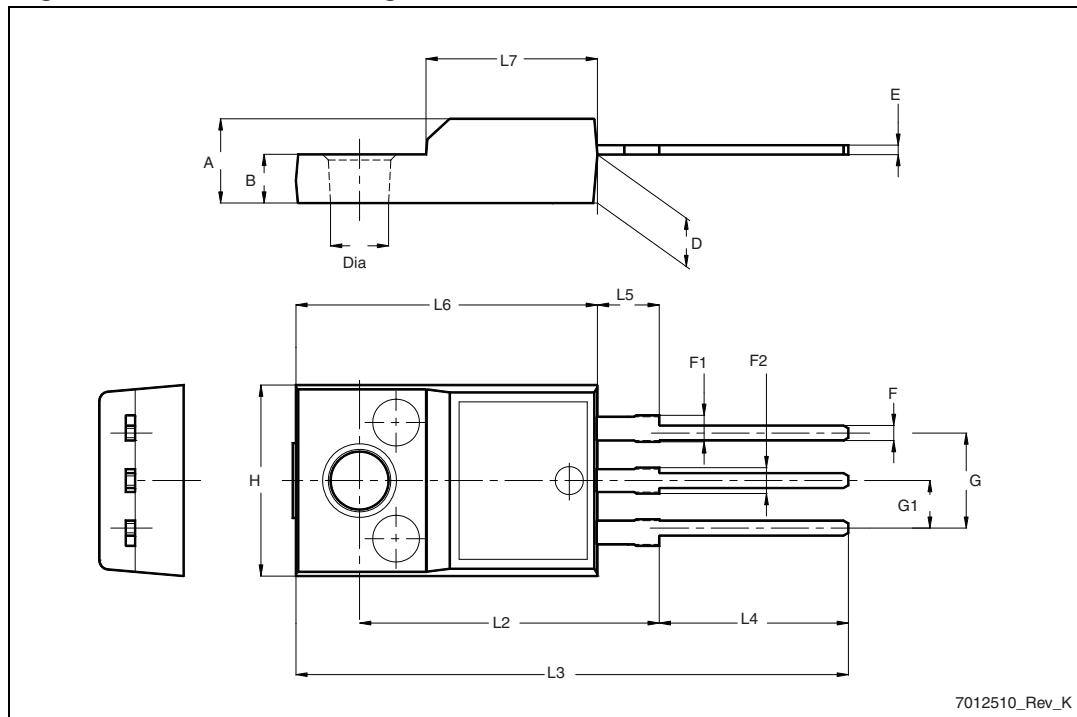


4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 9. TO-220FP mechanical data

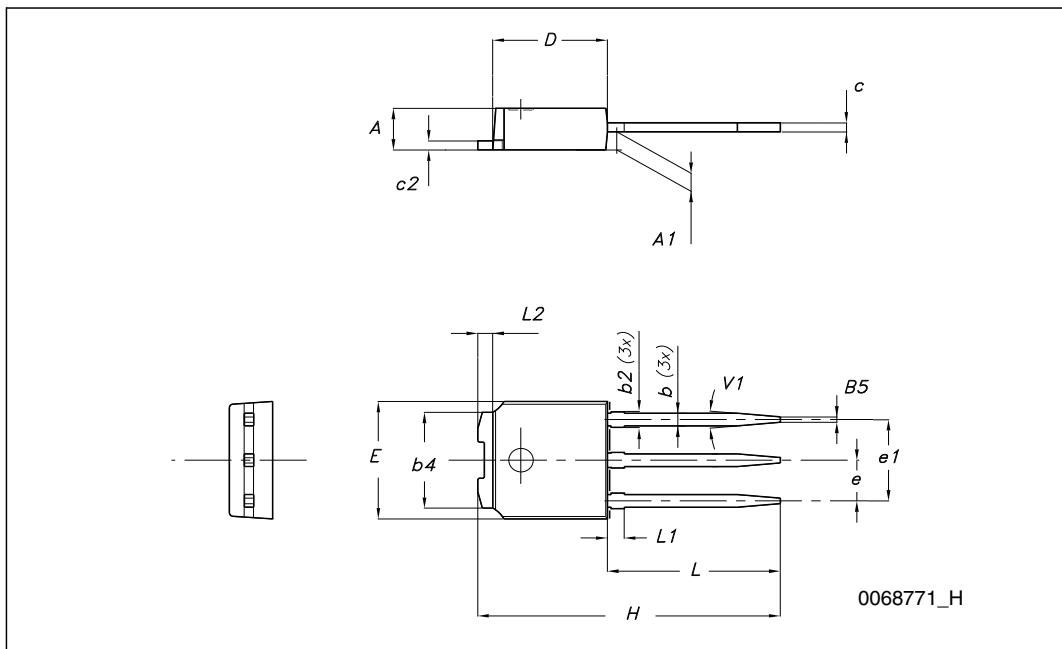
Dim.	mm		
	Min.	Typ.	Max.
A	4.4		4.6
B	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
H	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

Figure 23. TO-220FP drawing mechanical data

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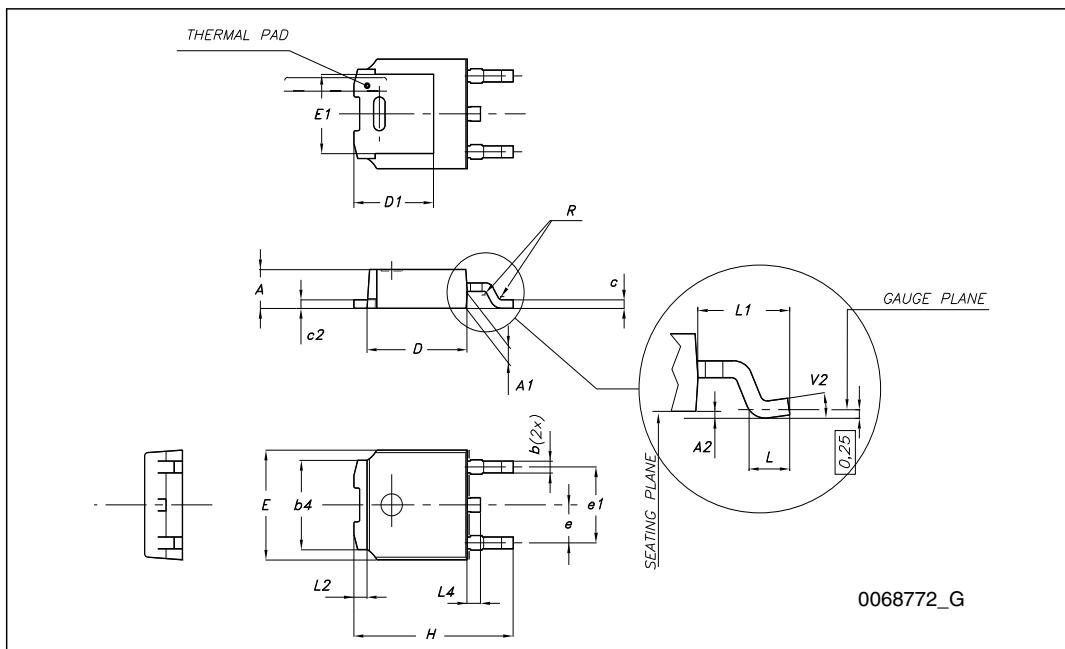
TO-251 (IPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
b	0.64		0.90
b2			0.95
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
E	6.40		6.60
e		2.28	
e1	4.40		4.60
H		16.10	
L	9.00		9.40
(L1)	0.80		1.20
L2		0.80	
V1		10°	



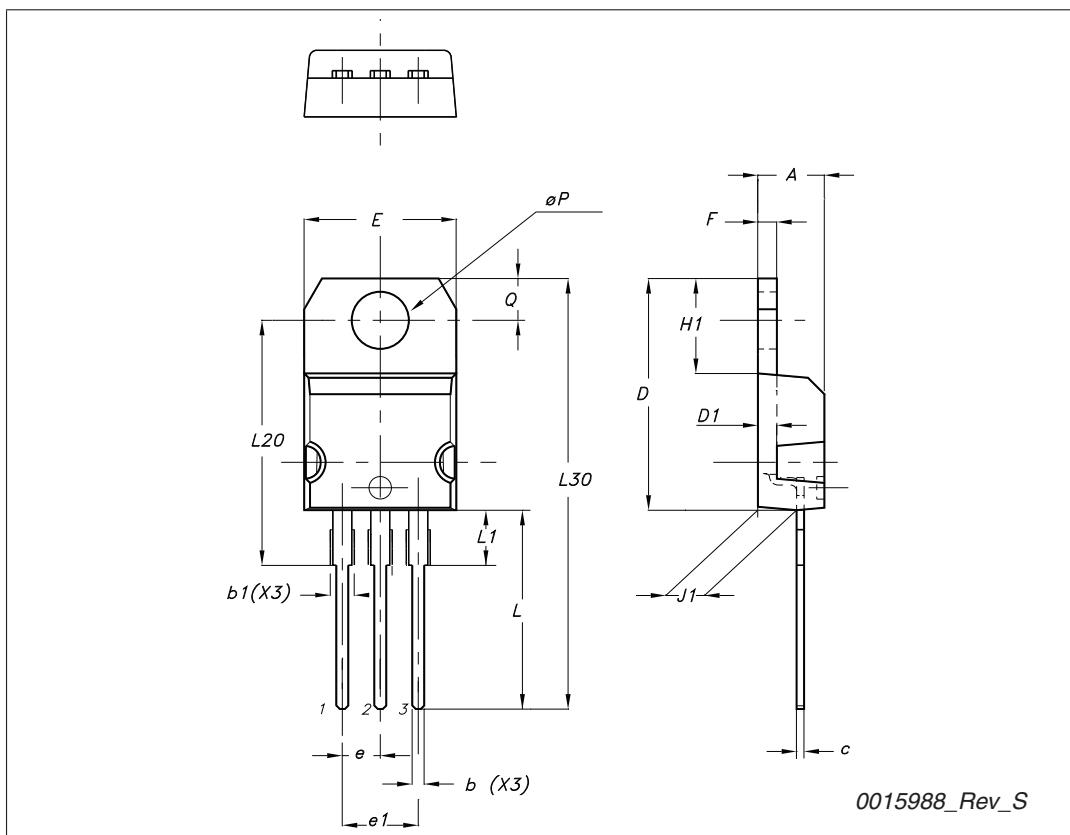
TO-252 (DPAK) mechanical data

DIM.	mm.		
	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
H	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °



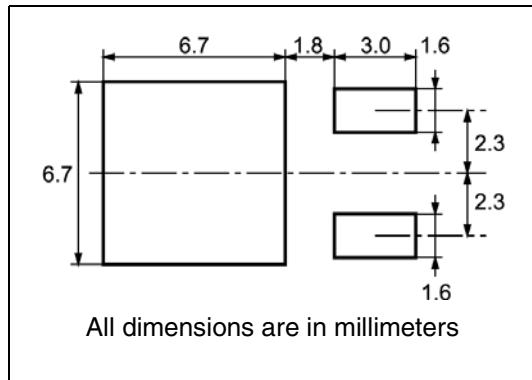
TO-220 type A mechanical data

Dim	mm		
	Min	Typ	Max
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95



5 Packaging mechanical data

DPAK FOOTPRINT



TAPE AND REEL SHIPMENT

REEL MECHANICAL DATA				
DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A		330		12.992
B	1.5		0.059	
C	12.8	13.2	0.504	0.520
D	20.2		0.795	
G	16.4	18.4	0.645	0.724
N	50		1.968	
T		22.4		0.881

TAPE MECHANICAL DATA				
DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A ₀	6.8	7	0.267	0.275
B ₀	10.4	10.6	0.409	0.417
B ₁		12.1		0.476
D	1.5	1.6	0.059	0.063
D ₁	1.5		0.059	
E	1.65	1.85	0.065	0.073
F	7.4	7.6	0.291	0.299
K ₀	2.55	2.75	0.100	0.108
P ₀	3.9	4.1	0.153	0.161
P ₁	7.9	8.1	0.311	0.319
P ₂	1.9	2.1	0.075	0.082
R	40		1.574	
W	15.7	16.3	0.618	0.641

The detailed diagrams and tables provide specific dimensions for the tape and reel assembly. Key features include:

- Reel Mechanical Data:** Dimensions A (330 mm), B (1.5 mm), C (12.8 mm), D (20.2 mm), G (16.4 mm), N (50 mm), and T (22.4 mm).
- Access Hole:** A circular access hole with a diameter of 40 mm is located at the slot location.
- Slot Dimensions:** The slot has a full radius and a minimum width of 2.5 mm.
- Base and Bulk Quantities:** Both are listed as 2500 units.
- Center Line of Cavity:** Indicated as the center line of the cavity.
- User Direction of Feed:** Indicated by an arrow pointing right.
- FEED DIRECTION:** Indicated by an arrow pointing right.
- Bending Radius:** Specified as R min.
- TRL:** Indicated as a tape loading fixture.
- Dimensions:** K₀, T, B₁, D, P₂, P₀, E, F, W, A₀, P₁, and B₀ are labeled with their respective values.

6 Revision history

Table 10. Document revision history

Date	Revision	Changes
29-Oct-2009	1	First release.
19-Jul-2010	2	Corrected values in <i>Table 3: Thermal data</i> .
11-Oct-2010	3	Inserted new value in <i>Table 6: Dynamic</i>
04-Nov-2010	4	Changed R _{DS(on)} typical value.

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- Техническая поддержка проекта;
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